

TXS0108E 8-Bit Bi-directional, Level-Shifting, Voltage Translator for Open-Drain and Push-Pull Applications

1 Features

- No Direction-Control Signal Needed
- Maximum Data Rates
 - 110 Mbps (Push Pull)
 - 1.2 Mbps (Open Drain)
- 1.2 V to 3.6 V on A Port and 1.65 V to 5.5 V on B Port ($V_{CCA} \leq V_{CCB}$)
- No Power-Supply Sequencing Required – Either V_{CCA} or V_{CCB} Can Be Ramped First
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22 (A Port)
 - 2000 V Human Body Model (A114-B)
 - 150 V Machine Model (A115-A)
 - 1000 V Charged-Device Model (C101)
- IEC 61000-4-2 ESD (B Port)
 - ± 8 kV Contact Discharge
 - ± 6 kV Air-Gap Discharge

2 Applications

- Handsets
- Smartphones
- Tablets
- Desktop PCs

3 Description

This 8-bit non-inverting translator uses two separate configurable power-supply rails. The A port tracks the V_{CCA} pin supply voltage. The V_{CCA} pin accepts any supply voltage between 1.2 V and 3.6 V. The B port tracks the V_{CCB} pin supply voltage. The V_{CCB} pin accepts any supply voltage between 1.65 V and 5.5 V. Two input supply pins allows for low Voltage bidirectional translation between any of the 1.2 V, 1.8 V, 2.5 V, 3.3 V, and 5 V voltage nodes.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance (Hi-Z) state.

To ensure the Hi-Z state during power-up or power-down periods, tie OE to GND through a pull-down resistor. The minimum value of the resistor is determined by the current-sourcing capability of the driver.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TXS0108EPW	TSSOP (20)	6.50 mm × 6.40 mm
TXS0108ERGY	VQFN (20)	4.50 mm × 3.50 mm
TXS0108EZXY	UFBGA (20)	3.00 mm × 2.50 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Application

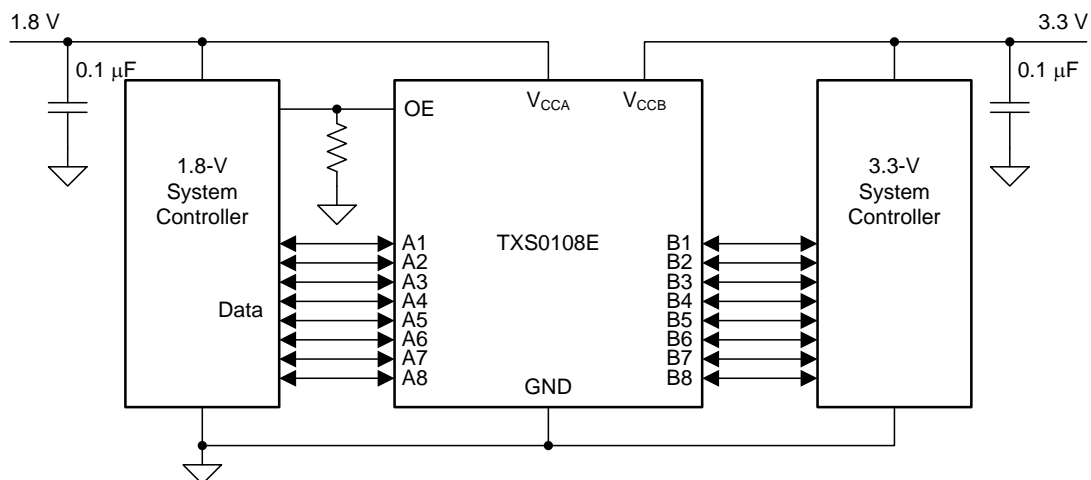


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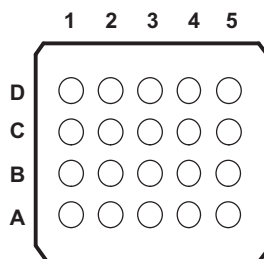
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4 Revision History

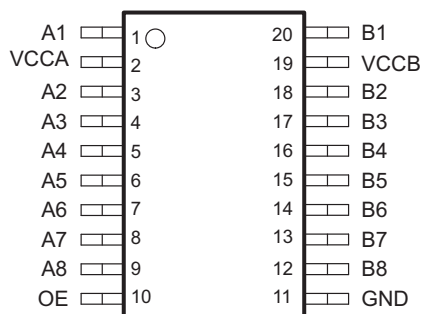
Changes from Revision D (February 2016) to Revision E	Page
• Added junction temperature	5
Changes from Revision C (December 2014) to Revision D	Page
• Made changes to <i>ESD Ratings</i>	1
Changes from Revision B (November 2013) to Revision C	Page
• Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1

5 Pin Configuration and Functions

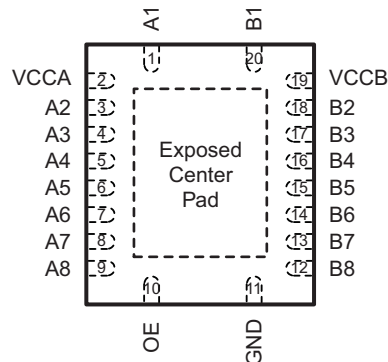
**ZXY PACKAGE
20 BUMP
(BOTTOM VIEW)**



**PW PACKAGE
20-PIN TSSOP
(TOP VIEW)**



**RGY PACKAGE
20 PINS
(TOP VIEW)**



The exposed center pad, if used, must be connected as a secondary ground or left electrically open.

Table 1. Pin Assignments

	1	2	3	4	5
D	VCCB	B2	B4	B6	B8
C	B1	B3	B5	B7	GND
B	A1	A3	A5	A7	OE
A	VCCA	A2	A4	A6	A8

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Pin Functions

PIN NO.			TYPE ⁽¹⁾	DESCRIPTION
NAME	PW, RGY	ZXY		
A1	1	B1	I/O	Input/output 1. Referenced to V_{CCA}
A2	3	A2	I/O	Input/output 2. Referenced to V_{CCA}
A3	4	B2	I/O	Input/output 3. Referenced to V_{CCA}
A4	5	A3	I/O	Input/output 4. Referenced to V_{CCA}
A5	6	B3	I/O	Input/output 5. Referenced to V_{CCA}
A6	7	A4	I/O	Input/output 6. Referenced to V_{CCA}
A7	8	B4	I/O	Input/output 7. Referenced to V_{CCA}
A8	9	A5	I/O	Input/output 8. Referenced to V_{CCA}
B1	20	C 1	I/O	Input/output 1. Referenced to V_{CCB}
B2	18	D2	I/O	Input/output 2. Referenced to V_{CCB}
B3	17	C2	I/O	Input/output 3. Referenced to V_{CCB}
B4	16	D3	I/O	Input/output 4. Referenced to V_{CCB}
B5	15	C3	I/O	Input/output 5. Referenced to V_{CCB}
B6	14	D4	I/O	Input/output 6. Referenced to V_{CCB}
B7	13	C4	I/O	Input/output 7. Referenced to V_{CCB}
B8	12	D5	I/O	Input/output 8. Referenced to V_{CCB}
GND	11	C5	—	Ground
OE	10	B5	I	Tri-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .
VCCA	2	A1	P	A-port supply voltage. $1.2\text{ V} \leq V_{CCA} \leq 3.6\text{ V}$, $V_{CCA} \leq V_{CCB}$.
VCCB	19	D1	P	B-port supply voltage. $1.65\text{ V} \leq V_{CCB} \leq 5.5\text{ V}$.
Thermal Pad			—	For the RGY package, the exposed center thermal pad must be either be connected to Ground or left electrically opened.

(1) I = input, O = output, I/O = input and output, P = power

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Supply voltage, V_{CCA}		–0.5	4.6	V
Supply voltage, V_{CCB}		–0.5	5.5	V
Input voltage, V_I ⁽²⁾	A port	–0.5	4.6	V
	B port	–0.5	6.5	
Voltage applied to any output in the high-impedance or power-off state, V_O ⁽²⁾	A port	–0.5	4.6	V
	B port	–0.5	6.5	
Voltage applied to any output in the high or low state, V_O ^{(2) (3)}	A port	–0.5	$V_{CCA} + 0.5$	V
	B port	–0.5	$V_{CCB} + 0.5$	V
Input clamp current, I_{IK}	$V_I < 0$		–50	mA
Output clamp current, I_{OK}	$V_O < 0$		–50	mA
Continuous output current, I_O		–50	50	mA
Continuous current through V_{CCA} , V_{CCB} , or GND		–100	100	mA
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative Voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	
	Machine model (MM)	±150	
	IEC 61000-4-2 ESD (B Port) Contact Discharge	±8000	
	IEC 61000-4-2 ESD (B Port) Air-Gap Discharge	±6000	

- (1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

				MIN	MAX	UNIT
V _{CCA}	Supply voltage ⁽³⁾			1.2	3.6	V
V _{CCB}	Supply voltage ⁽³⁾			1.65	5.5	V
V _{IH}	High-level input voltage	A-Port I/Os	V _{CCA} (V) = 1.2 to 1.95	V _{CCB} (V) = 1.65 to 5.5	V _{CCI} – 0.2	V _{CCI}
			V _{CCA} (V) = 1.95 to 3.6	V _{CCB} (V) = 1.65 to 5.5	V _{CCI} – 0.4	V _{CCI}
		B-Port I/Os	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5	V _{CCI} – 0.4	V _{CCI}
			OE	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5	V _{CCA} × 0.65
V _{IL}	Low-level input voltage	A-Port I/Os	V _{CCA} (V) = 1.2 to 1.95	V _{CCB} (V) = 1.65 to 5.5	0	0.15
			V _{CCA} (V) = 1.95 to 3.6	V _{CCB} (V) = 1.65 to 5.5	0	0.15
		B-Port I/Os	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5	0	0.15
			OE	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5	0 V _{CCA} × 0.35
Δt/Δv	Input transition rise or fall rate	A-Port I/Os Push-pull	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5		10 ns/V
		B-Port I/Os Push-pull	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5		10 ns/V
		Control input	V _{CCA} (V) = 1.2 to 3.6	V _{CCB} (V) = 1.65 to 5.5		10 ns/V
T _A	Operating free-air temperature			–40	125	°C

(1) V_{CCI} is the V_{CC} associated with the data input port.

(2) V_{CCO} is the V_{CC} associated with the output port.

(3) V_{CCA} must be less than or equal to V_{CCB}, and V_{CCA} must not exceed 3.6 V.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TXS0108E			UNIT
		PW (TSSOP)	RGY	ZXY	
		20 PINS	20 PINS	20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	101.5	34.7	101.5	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	35.9	39.5	35.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	52.4	12.7	52.4	°C/W
ψ _{JT}	Junction-to-top characterization parameter	2.3	0.9	2.3	°C/W
ψ _{JB}	Junction-to-board characterization parameter	51.9	12.7	51.9	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	—	7.5	—	°C/W

(1) For more information about traditional and new thermal metrics, see the [IC Package Thermal Metrics application report](#).

6.5 Electrical Characteristics: $T_A = -40^{\circ}\text{C}$ to 85°C ⁽¹⁾⁽²⁾⁽³⁾

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CCA} (V)	V_{CCB} (V)	$T_A = 25^{\circ}\text{C}$			$T_A = -40^{\circ}\text{C}$ to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
V_{OHA} Port A output high voltage	$I_{OH} = -20\ \mu\text{A}$ $V_{IB} \geq V_{CCB} - 0.4\ \text{V}$	1.2	1.65 to 5.5	$V_{CCA} \times 0.67$					V
V_{OLA} Port A output low voltage	$I_{OL} = 135\ \mu\text{A}$, $V_{IB} \leq 0.15\ \text{V}$	1.2	1.65 to 5.5	0.25					V
	$I_{OL} = 180\ \mu\text{A}$, $V_{IB} \leq 0.15\ \text{V}$	1.4	1.65 to 5.5					0.4	
	$I_{OL} = 220\ \mu\text{A}$, $V_{IB} \leq 0.15\ \text{V}$	1.65	1.65 to 5.5					0.4	
	$I_{OL} = 300\ \mu\text{A}$, $V_{IB} \leq 0.15\ \text{V}$	2.3	1.65 to 5.5					0.4	
	$I_{OL} = 400\ \mu\text{A}$, $V_{IB} \leq 0.15\ \text{V}$	3	1.65 to 5.5					0.55	
V_{OHB} Port B output high voltage	$I_{OH} = -20\ \mu\text{A}$, $V_{IA} \geq V_{CCA} - 0.2\ \text{V}$	1.2	1.65 to 5.5	$V_{CCB} \times 0.67$					V
V_{OLB} Port B output low voltage	$I_{OL} = 220\ \mu\text{A}$, $V_{IA} \leq 0.15\ \text{V}$	1.2 to 3.6	1.65					0.4	V
	$I_{OL} = 300\ \mu\text{A}$, $V_{IA} \leq 0.15\ \text{V}$	1.2 to 3.6	2.3					0.4	
	$I_{OL} = 400\ \mu\text{A}$, $V_{IA} \leq 0.15\ \text{V}$	1.2 to 3.6	3					0.55	
	$I_{OL} = 620\ \mu\text{A}$, $V_{IA} \leq 0.15\ \text{V}$	1.2 to 3.6	4.5					0.55	
I_I Input leakage current	OE: $V_I = V_{CCI}$ or GND	1.2	1.65 to 5.5	-1		1		2	μA
I_{OZ} High-impedance state output current	A or B port	1.2	1.65 to 5.5	-1		1	-2	2	μA
I_{CCA} V_{CCA} supply current	$V_I = V_O = \text{Open}$, $I_O = 0$	1.2	1.65 to 5.5	1.5			-2	2	μA
		1.5 to 3.6	2.3 to 5.5					2	
		3.6	0					2	
		0	5.5					-1	
I_{CCB} V_{CCB} supply current	$V_I = V_O = \text{Open}$, $I_O = 0$	1.2	1.65 to 5.5	1.5					μA
		1.5 to 3.6	2.3 to 5.5					6	
		3.6	0					-1	
		0	5.5					1.2	
$I_{CCA} + I_{CCB}$ Combined supply current	$V_I = V_{CCI}$ or GND, $I_O = 0$	1.2	2.3 to 5.5	3					μA
		1.5 to 3.6	2.3 to 5.5					8	
I_{CCZA} High-impedance state V_{CCA} supply current	$V_I = V_O = \text{Open}$, $I_O = 0$, OE = GND	1.2	1.65 to 5.5	0.05					μA
I_{CCZB} High-impedance state V_{CCB} supply current	$V_I = V_O = \text{Open}$, $I_O = 0$, OE = GND	1.2	1.65 to 5.5	4					μA
C_i Input capacitance	OE	3.3	3.3	4.5				5.5	pF
C_{io} Input-to-output internal capacitance	A port	3.3	3.3	6				7	pF
	B port	3.3	3.3	5.5				6	

- (1) V_{CCO} is the V_{CC} associated with the output port.
- (2) V_{CCI} is the V_{CC} associated with the input port.
- (3) V_{CCA} must be less than or equal to V_{CCB} , and V_{CCA} must not exceed 3.6 V.

6.6 Timing Requirements: $V_{CCA} = 1.2 \text{ V}$

 $T_A = 25^\circ\text{C}$, $V_{CCA} = 1.2 \text{ V}$

			$V_{CCB} \text{ (V)}$				UNIT
			1.8 (TYP)	2.5 (TYP)	3.3 (TYP)	5 (TYP)	
Data rate	Push-pull		20	20	20	20	Mbps
	Open-drain		2	2	2	2	
t_w Pulse duration	Data inputs	Push-pull	50	50	50	50	ns
		Open-drain	500	500	500	500	

6.7 Timing Requirements: $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

			$V_{CC\ B} = 1.8\ V$ $\pm 0.15\ V$		$V_{CC\ B} = 2.5\ V$ $\pm 0.2\ V$		$V_{CC\ B} = 3.3\ V$ $\pm 0.3\ V$		$V_{CC\ B} = 5\ V$ $\pm 0.5\ V$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Push-pull		40		60		60		50		Mbps
	Open-drain		2		2		2		2		
t_w Pulse duration	Data inputs	Push-pull	25		16.7		16.7		20		ns
		Open-drain	500		500		500		500		

6.8 Timing Requirements: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

			$V_{CC\ B} = 1.8\ V$ $\pm 0.15\ V$		$V_{CC\ B} = 2.5\ V$ $\pm 0.2\ V$		$V_{CC\ B} = 3.3\ V$ $\pm 0.3\ V$		$V_{CC\ B} = 5\ V$ $\pm 0.5\ V$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Push-pull		40		60		60		60		Mbps
	Open-drain		2		2		2		2		
t_w Pulse duration	Data inputs	Push-pull	25		16.7		16.7		16.7		ns
		Open-drain	500		500		500		500		

6.9 Timing Requirements: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

				$V_{CCB} = 2.5\text{ V}$ $\pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V}$ $\pm 0.3\text{ V}$		$V_{CC} = 5\text{ V}$ $\pm 0.5\text{ V}$		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Push-pull			60	60	60	Mbps			
	Open-drain			2	2	2				
t_w	Pulse duration	Data inputs	Push-pull	16.7	16.7	16.7	ns			
			Open-drain	500	500	500				

6.10 Timing Requirements: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

			$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		UNIT
			MIN	MAX	MIN	MAX	
Data rate	Push-pull		60		60		Mbps
	Open-drain		2		2		
t_w	Pulse duration	Data inputs	Push-pull	16.7	16.7		ns
			Open-drain	500	500		

6.11 Switching Characteristics: $V_{CCA} = 1.2\text{ V}$

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		$V_{CCB} = 1.8\text{ V}$ $\pm 0.15\text{ V}$			$V_{CCB} = 2.5\text{ V}$ $\pm 0.2\text{ V}$			$V_{CCB} = 3.3\text{ V}$ $\pm 0.3\text{ V}$			$V_{CCB} = 5\text{ V}$ $\pm 0.5\text{ V}$			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{PHL} Propagation delay time (high-to-low output)	A-to-B	Push-pull driving		6.5			5.9			5.7			5.5		ns
		Open-drain driving		11.9			11.1			11			11.1		
t_{PLH} Propagation delay time (low-to-high output)	A-to-B	Push-pull driving		7.1			6.3			6.2			6.6		
		Open-drain driving		293			236			197			152		
t_{PHL} Propagation delay time (high-to-low output)	B-to-A	Push-pull driving		6.4			6			5.8			5.6		ns
		Open-drain driving		8.5			6.8			6.2			5.9		
t_{PLH} Propagation delay time (low-to-high output)	B-to-A	Push-pull driving		5.6			4.1			3.6			3.2		
		Open-drain driving		312			248			192			132		
t_{en} Enable time	OE-to-A or B	Push-pull driving		200			200			200			200		ns
t_{dis} Disable time	OE-to-A or B	Push-pull driving		16.8			13.9			13.2			13.5		ns
t_{rA} Input rise time	A-port rise time	Push-pull driving		7.9			6.7			6.5			6.4		ns
		Open-drain driving		296			238			185			127		
t_{rB} Input rise time	B-port rise time	Push-pull driving		6.3			3.3			1.8			1.5		ns
		Open-drain driving		236			164			115			60		
t_{fA} Input fall time	A-port fall time	Push-pull driving		5.8			4.8			4.3			3.8		ns
		Open-drain driving		5.9			4.7			4.1			3.5		
t_{fB} Input fall time	B-port fall time	Push-pull driving		4.6			2.8			2.2			1.9		
		Open-drain driving		4.5			2.7			2.2			1.9		
$t_{SK(O)}$ Skew (time), output	Channel -to- channel skew	Push-pull driving		1			1			1			1		ns
Maximum data rate	A or B	Push-pull driving		20			20			20			20		Mbps
		Open-drain driving		2			2			2			2		

6.12 Switching Characteristics: $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PHL}	Propagation delay time (high-to-low output)	A-to-B	Push-pull driving	11		9.2		8.6		8.6		ns
			Open-drain driving	4	14.4	3.6	12.8	3.5	12.2	3.5	12	
t _{PLH}	Propagation delay time (low-to-high output)	A-to-B	Push-pull driving	12		10		9.8		9.7		
			Open-drain driving	182	720	143	554	114	473	81	384	
t _{PHL}	Propagation delay time (high-to-low output)	B-to-A	Push-pull driving	12.7		11.1		11		12		ns
			Open-drain driving	3.4	13.2	3.1	9.6	2.8	8.5	2.5	7.5	
t _{PLH}	Propagation delay time (low-to-high output)	B-to-A	Push-pull driving	9.5		6.2		5.1		1.6		
			Open-drain driving	186	745	147	603	118	519	84	407	
t _{en}	Enable time	OE-to-A or B	Push-pull driving	200		200		200		200		ns
t _{dis}	Disable time	OE-to-A or B	Push-pull driving	28.1		22		20.1		19.6		ns
t _{rA}	Input rise time	A-port rise time	Push-pull driving	3.5	13.1	3	9.8	3.1	9	3.2	8.3	ns
			Open-drain driving	147	982	115	716	92	592	66	481	
t _{rB}	Input rise time	B-port rise time	Push-pull driving	2.9	11.4	1.9	7.4	0.9	4.7	0.7	2.6	ns
			Open-drain driving	135	1020	91	756	58	653	20	370	
t _{fA}	Input fall time	A-port fall time	Push-pull driving	2.3	9.9	1.7	7.7	1.6	6.8	1.7	6	ns
			Open-drain driving	2.4	10	2.1	7.9	1.7	7	1.5	6.2	
t _{fB}	Input fall time	B-port fall time	Push-pull driving	2	8.7	1.3	5.5	0.9	3.8	0.8	3.1	
			Open-drain driving	1.2	11.5	1.3	8.6	1	9.6	0.5	7.7	
t _{SK(O)}	Skew (time), output	Channel-to-channel skew	Push-pull driving	1		1	1	1.1		1		ns
	Maximum data rate	A or B	Push-pull driving	40		60		60		50		Mbps
			Open-drain driving	2		2		2		2		

6.13 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PHL} Propagation delay time (high-to-low output)	A-to-B	Push-pull driving		8.2		6.4		5.7		5.6	ns
		Open-drain driving	3.6	11.4	3.2	9.9	3.1	9.3	3.1	8.9	
t_{PLH} Propagation delay time (low-to-high output)	A-to-B	Push-pull driving		9		2.1		6.5		6.3	
		Open-drain driving	194	729	155	584	126	466	90	346	
t_{PHL} Propagation delay time (high-to-low output)	B-to-A	Push-pull driving		9.8		8		7.4		7	ns
		Open-drain driving	3.4	12.1	2.8	8.5	2.5	7.3	2.1	6.2	
t_{PLH} Propagation delay time (low-to-high output)	B-to-A	Push-pull driving		10.2		7		5.8		5	
		Open-drain driving	197	733	159	578	129	459	93	323	
t_{en} Enable time	OE-to-A or B	Push-pull driving		200		200		200		200	ns
t_{dis} Disable time	OE-to-A or B	Push-pull driving		25.1		18.8		16.5		15.3	ns
t_{rA} Input rise time	A-port rise time	Push-pull driving	3.1	11.9	2.6	8.6	2.7	7.8	2.8	7.2	ns
		Open-drain driving	155	996	124	691	100	508	72	350	
t_{rB} Input rise time	B-port rise time	Push-pull driving	2.8	10.5	1.8	7.2	1.2	5.2	0.7	2.7	ns
		Open-drain driving	132	1001	106	677	73	546	32	323	
t_{fA} Input fall time	A-port fall time	Push-pull driving	2.1	8.8	1.6	6.6	1.4	5.7	1.4	4.9	ns
		Open-drain driving	2.2	9	1.7	6.7	1.4	5.8	1.2	5.2	
t_{fB} Input fall time	B-port fall time	Push-pull driving	2	8.3	1.3	5.4	0.9	3.9	0.7	3	
		Open-drain driving	0.8	10.5	0.7	10.7	1	9.6	0.6	7.8	
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew	Push-pull driving		1		1		1		1	ns
Maximum data rate	A or B	Push-pull driving	40		60		60		60		Mbps
		Open-drain driving	2		2		2		2		

6.14 Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_{PHL} Propagation delay time (high-to-low output)	A -to-B	Push-pull driving		5		4		3.7	ns
		Open-drain driving	2.4	6.9	2.3	6.3	2.2	5.8	
t_{PLH} Propagation delay time (low-to-high output)	A -to-B	Push-pull driving		5.2		4.3		3.9	ns
		Open-drain driving	149	592	125	488	93	368	
t_{PHL} Propagation delay time (high-to-low output)	B-to-A	Push-pull driving		5.4		4.7		4.2	ns
		Open-drain driving	2.5	7.3	2.2	6	1.8	4.9	
t_{PLH} Propagation delay time (low-to-high output)	B-to-A	Push-pull driving		5.9		4.4		3.5	ns
		Open-drain driving	150	595	126	481	94	345	
t_{en} Enable time	OE-to-A or B	Push-pull driving		200		200		200	ns
t_{dis} Disable time	OE-to-A or B	Push-pull driving		15.7		12.9		11.2	ns
t_{rA} Input rise time	A-port rise time	Push-pull driving	2	7.3	2.1	6.4	2.2	5.8	ns
		Open-drain driving	110	692	93	529	68	369	
t_{rB} Input rise time	B-port rise time	Push-pull driving	1.8	6.5	1.3	5.1	0.7	3.4	ns
		Open-drain driving	107	693	79	483	41	304	
t_{fA} Input fall time	A-port fall time	Push-pull driving	1.5	5.7	1.2	4.7	1.3	3.8	ns
		Open-drain driving	1.5	5.6	1.2	4.7	1.1	4	
t_{fB} Input fall time	B-port fall time	Push-pull driving	1.4	5.4	0.9	4.1	0.7	3	ns
		Open-drain driving	0.4	14.2	0.5	19.4	0.4	3	
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew	Push-pull driving		1		1.2		1	ns
Maximum data rate	A or B	Push-pull driving	60		60		60		Mbps
		Open-drain driving	2		2		2		

6.15 Switching Characteristics: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$		UNIT
				MIN	MAX	MIN	MAX	
t_{PHL}	Propagation delay time (high-to-low output)	A-to-B	Push-pull driving		3.8		3.1	ns
			Open-drain driving	2	5.3	1.9	4.8	
t_{PLH}	Propagation delay time (low-to-high output)	A-to-B	Push-pull driving		3.9		3.5	
			Open-drain driving	111	439	87	352	
t_{PHL}	Propagation delay time (high-to-low output)	B-to-A	Push-pull driving		4.2		3.8	ns
			Open-drain driving	2.1	5.5	1.7	4.5	
t_{PLH}	Propagation delay time (low-to-high output)	A-to-B	Push-pull driving		3.8		4.3	
			Open-drain driving	112	449	86	339	
t_{en}	Enable time	OE-to-A or B	Push-pull driving		200		200	ns
t_{dis}	Disable time	OE-to-A or B	Push-pull driving		11.9		9.8	ns
t_{rA}	Input rise time	A-port rise time	Push-pull driving	1.8	5.7	1.9	5	ns
			Open-drain driving	75	446	57	337	
t_{rB}	Input rise time	B-port rise time	Push-pull driving	1.5	5	1	3.6	ns
			Open-drain driving	72	427	40	290	
t_{fA}	Input fall time	A-port fall time	Push-pull driving	1.2	4.5	1.1	3.5	ns
			Open-drain driving	1.1	4.4	1	3.7	
t_{fB}	Input fall time	B-port fall time	Push-pull driving	1.1	4.2	0.8	3.1	
			Open-drain driving	1	4.2	0.8	3.1	
$t_{SK(O)}$	Skew (time), output	Channel-to-channel skew	Push-pull driving		1		1	ns
	Maximum data rate	A or B	Push-pull driving	60		60		Mbps
			Open-drain driving	2		2		

6.16 Operating Characteristics: $V_{CCA} = 1.2\text{ V}$ to 1.5 V , $V_{CCB} = 1.2\text{ V}$ to 1.5 V

 $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		V _{CCA} = 1.2 V, V _{CCB} = 1.2 V			V _{CCA} = 1.2 V, V _{CCB} = 1.2 V			V _{CCA} = 1.5 V, V _{CCB} = 1.5 V			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
C _{pdA} Power dissipation capacitance	CL = 0 f = 10 MHz tr= tf= 1 ns OE = V _{CCA} (outputs enabled)	A-port input, B-port output	5.9			5.7			5.9			pF	
		B-port input, A-port output	10.2			10.3			9.9				
C _{pdB} Power dissipation capacitance		A-port input, B-port output	29.9			22.2			21.5				
		B-port input, A-port output	22.9			16.7			16.7				
C _{pdA} Power dissipation capacitance	CL = 0 f = 10 MHz tr= tf= 1 ns OE = V _{CCA} (outputs enabled)	A-port input, B-port output	0.01			0.01			0.01			pF	
		B-port input, A-port output	0.06			0.01			0.01				
C _{pdB} Power dissipation capacitance		A-port input, B-port output	0.06			0.01			0.01				
		B-port input, A-port output	0.06			0.01			0.01				

6.17 Operating Characteristics: $V_{CCA} = 1.8\text{ V}$ to 3.3 V , $V_{CCB} = 1.8\text{ V}$ to 3.3 V

 $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		V _{CCA} = 1.8 V, V _{CCB} = 1.8 V			V _{CCA} = 2.5 V, V _{CCB} = 2.5 V			V _{CCA} = 2.5 V, V _{CCB} = 2.5 V			V _{CCA} = 3.3 V, V _{CCB} = 3.3 V			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
C _{pdA}	Power dissipation capacitance	CL = 0 f = 10 MHz tr= tf= 1 ns OE = V _{CCA} (outputs enabled)	A-port input, B-port output	5.9			6.7			6.9			8			pF
			B-port input, A-port output	9.7			9.7			9.4			9.8			
C _{pdB}	Power dissipation capacitance		A-port input, B-port output	20.8			21			23.4			23			
			B-port input, A-port output	16.8			17.8			20.8			20.9			
C _{pdA}	Power dissipation capacitance	CL = 0 f = 10 MHz tr= tf= 1 ns OE = V _{CCA} (outputs enabled)	A-port input, B-port output	0.01			0.01			0.01			0.01			pF
			B-port input, A-port output	0.01			0.01			0.01			0.01			
C _{pdB}	Power dissipation capacitance		A-port input, B-port output	0.01			0.01			0.03			0.02			
			B-port input, A-port output	0.01			0.01			0.03			0.02			

7 Typical Characteristics

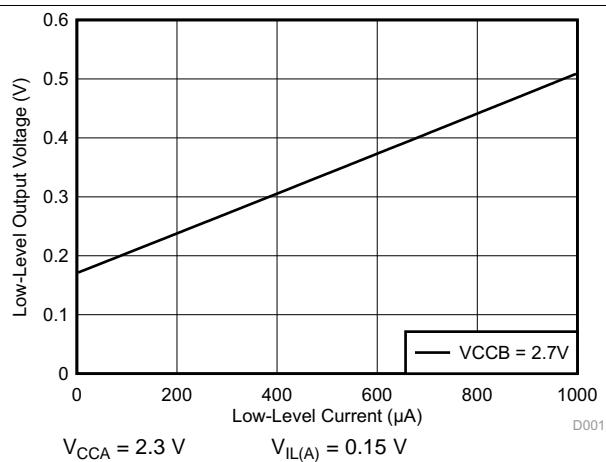


Figure 1. Low-Level Output Voltage ($V_{OL(Bx)}$) vs Low-Level Current ($I_{OL(Bx)}$)

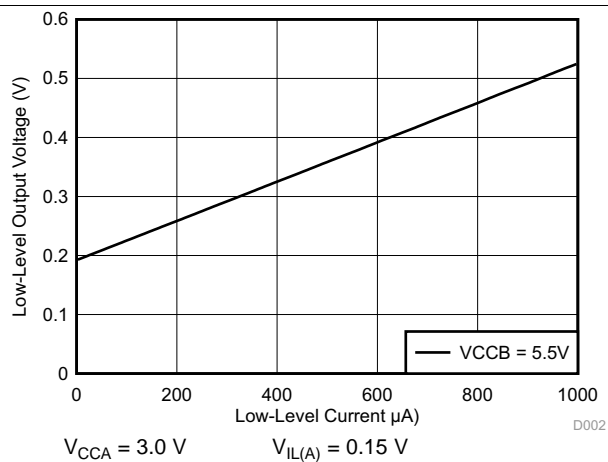


Figure 2. Low-Level Output Voltage ($V_{OL(Bx)}$) vs Low-Level Current ($I_{OL(Bx)}$)

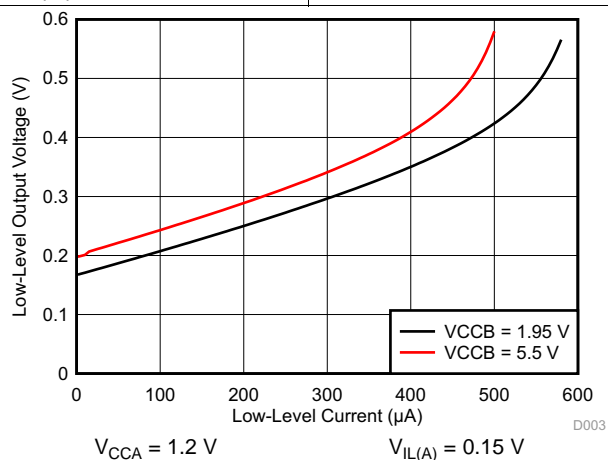
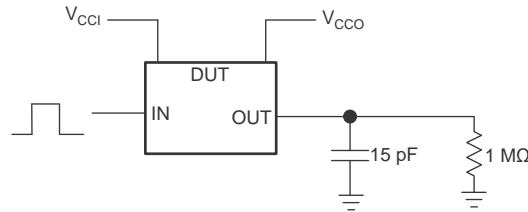


Figure 3. Low-Level Output Voltage ($V_{OL(Bx)}$) vs Low-Level Current ($I_{OL(Bx)}$)

8 Parameter Measurement Information

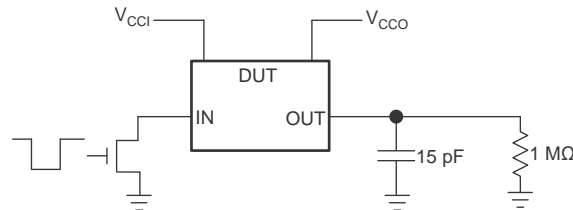
8.1 Load Circuits

Figure 4 shows the push-pull driver circuit used for measuring data rate, pulse duration, propagation delay, output rise-time and fall-time. Figure 5 shows the open-drain driver circuit used for measuring data rate, pulse duration, propagation delay, output rise-time and fall-time.



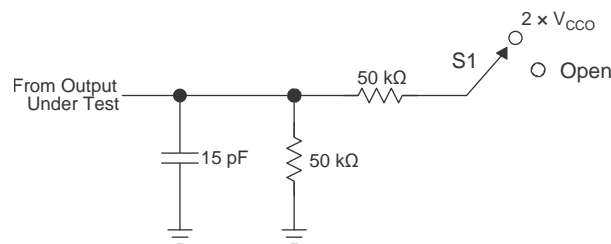
- (1) V_{CCI} is the V_{CC} associated with the input port.
- (2) V_{CCO} is the V_{CC} associated with the output port.

Figure 4. Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time And Fall-Time Measurement Using a Push-Pull Driver



- (1) V_{CCI} is the V_{CC} associated with the input port.
- (2) V_{CCO} is the V_{CC} associated with the output port.

Figure 5. Data Rate (10 pF), Pulse Duration (10 pF), Propagation Delay, Output Rise-Time And Fall-Time Measurement Using an Open-Drain Driver



TEST	S1
t_{PZL} , t_{PLZ} (t_{dis})	$2 \times V_{CCO}$
t_{PHZ} , t_{PZH} (t_{en})	Open

- (1) t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- (2) t_{PZL} and t_{PZH} are the same as t_{en} .

Figure 6. Load Circuit for Enable-Time and Disable-Time Measurement

8.2 Voltage Waveforms

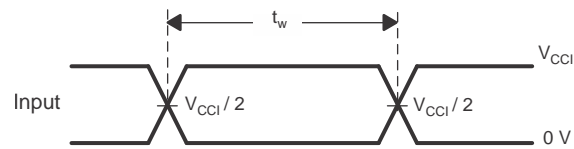


Figure 7. Pulse Duration (Push-Pull)

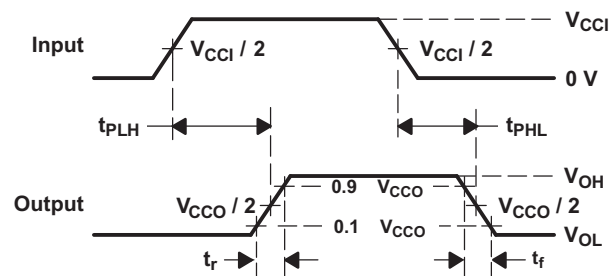


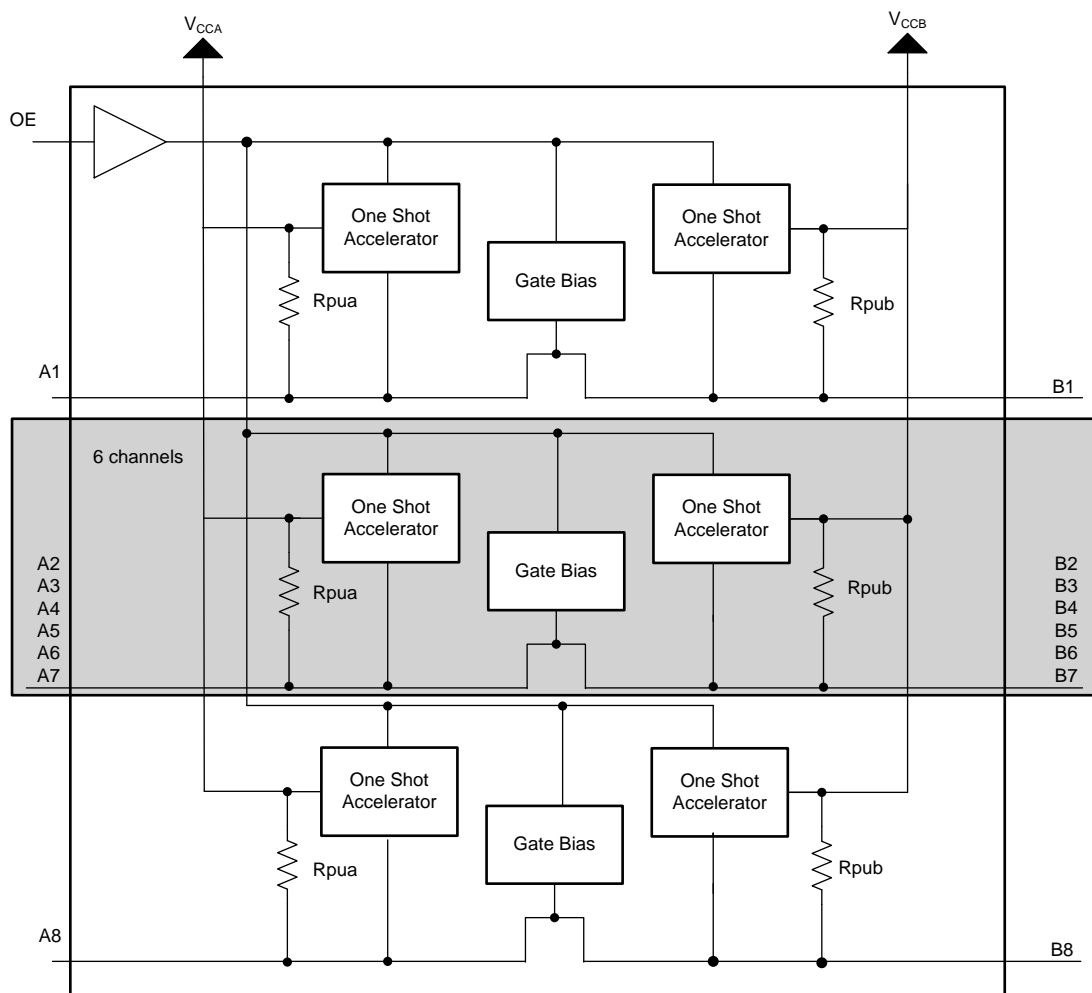
Figure 8. Propagation Delay Times

9 Detailed Description

9.1 Overview

The TXS0108E device is a directionless voltage-level translator specifically designed for translating logic voltage levels. The A-port accepts I/O voltages ranging from 1.2 V to 3.6 V. The B-port accepts I/O voltages from 1.65 V to 5.5 V. The device uses pass gate architecture with edge rate accelerators (one shots) to improve the overall data rate. The pull-up resistors, commonly used in open-drain applications, have been conveniently integrated so that an external resistor is not needed. While this device is designed for open-drain applications, the device can also translate push-pull CMOS logic outputs.

9.2 Functional Block Diagram



Each A-port I/O has a pull-up resistor (R_{PUA}) to V_{CCA} and each B-port I/O has a pull-up resistor (R_{PUB}) to V_{CCB} . R_{PUA} and R_{PUB} have a value of 40 k Ω when the output is driving low. R_{PUA} and R_{PUB} have a value of 4 k Ω when the output is driving high. R_{PUA} and R_{PUB} are disabled when OE = Low.

9.3 Feature Description

9.3.1 Architecture

Figure 9 describes semi-buffered architecture design this application requires for both push-pull and open-drain mode. This application uses edge-rate accelerator circuitry (for both the high-to-low and low-to-high edges), a high-on-resistance N-channel pass-gate transistor (on the order of 300 Ω to 500 Ω) and pull-up resistors (to provide DC-bias and drive capabilities) to meet these requirements. This design needs no direction-control signal (to control the direction of data flow from A to B or from B to A). The resulting implementation supports both low-speed open-drain operation as well as high-speed push-pull operation.

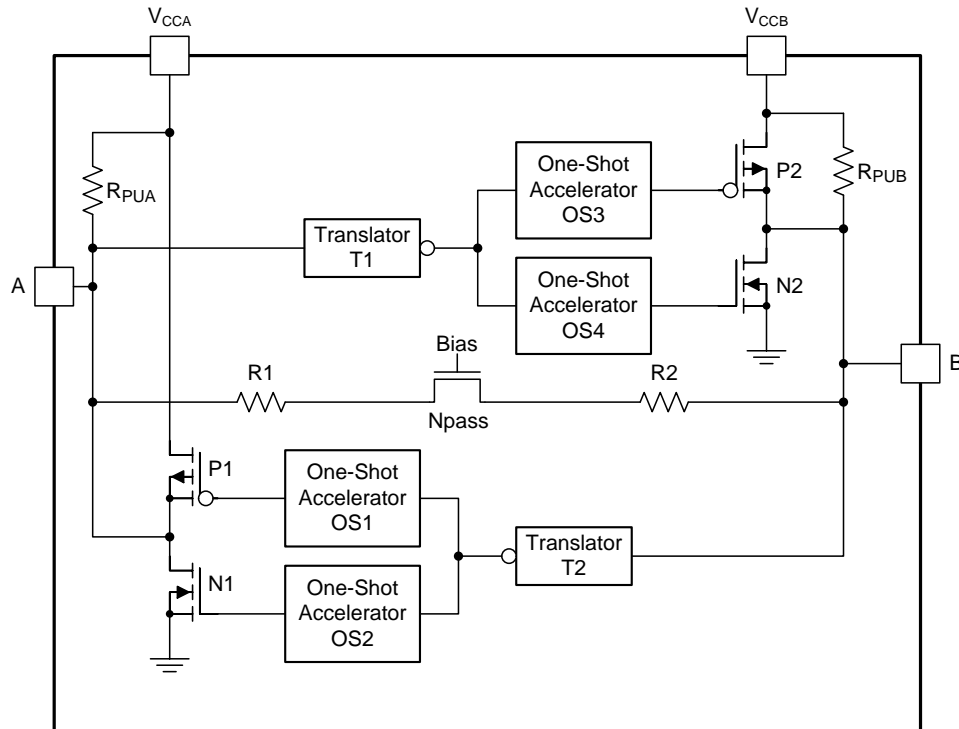


Figure 9. Architecture of a TXS0108E Cell

When transmitting data from A-ports to B-ports, during a rising edge the one-shot circuit (OS3) turns on the PMOS transistor (P2) for a short-duration which reduces the low-to-high transition time. Similarly, during a falling edge, when transmitting data from A to B, the one-shot circuit (OS4) turns on the N-channel MOSFET transistor (N2) for a short-duration which speeds up the high-to-low transition. The B-port edge-rate accelerator consists of one-shot circuits OS3 and OS4. Transistors P2 and N2 and serves to rapidly force the B port high or low when a corresponding transition is detected on the A port.

When transmitting data from B- to A-ports, during a rising edge the one-shot circuit (OS1) turns on the PMOS transistor (P1) for a short-duration which reduces the low-to-high transition time. Similarly, during a falling edge, when transmitting data from B to A, the one-shot circuit (OS2) turns on NMOS transistor (N1) for a short-duration and this speeds up the high-to-low transition. The A-port edge-rate accelerator consists of one-shots OS1 and OS2, transistors P1 and N1 components and form the edge-rate accelerator and serves to rapidly force the A port high or low when a corresponding transition is detected on the B port.

Feature Description (continued)

9.3.2 Input Driver Requirements

The continuous DC-current *sinking* capability is determined by the external system-level open-drain (or push-pull) drivers that are interfaced to the TXS0108E I/O pins. Because the high bandwidth of these bidirectional I/O circuits is used to facilitate this fast change from an input to an output and an output to an input, they have a modest DC-current *sourcing* capability of hundreds of micro-amperes, as determined by the internal pull-up resistors.

The fall time (t_{fA} , t_{fB}) of a signal depends on the edge-rate and output impedance of the external device driving TXS0108E data I/Os, as well as the capacitive loading on the data lines.

Similarly, the t_{PHL} and maximum data rates also depend on the output impedance of the external driver. The values for t_{fA} , t_{fB} , t_{PHL} , and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50 Ω .

9.3.3 Output Load Considerations

TI recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper one-shot triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The one-shot circuits have been designed to stay on for approximately 30 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The one-shot duration has been set to best optimize trade-offs between dynamic I_{CC} , load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance of the TXS0108E output. Therefore, TI recommends that this lumped-load capacitance is considered in order to avoid one-shot retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

9.3.4 Enable and Disable

The TXS0108E has an OE pin input that is used to disable the device by setting the OE pin low, which places all I/Os in the Hi-Z state. The disable time (t_{dis}) indicates the delay between the time when the OE pin goes low and when the outputs actually get disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the design must allow for the one-shot circuitry to become operational after the OE pin goes high.

9.3.5 Pull-up or Pull-down Resistors on I/O Lines

The TXS0108E has the smart pull-up resistors dynamically change value based on whether a low or a high is being passed through the I/O line. Each A-port I/O has a pull-up resistor (R_{PUA}) to V_{CCA} and each B-port I/O has a pull-up resistor (R_{PUB}) to V_{CCB} . R_{PUA} and R_{PUB} have a value of 40 k Ω when the output is driving low. R_{PUA} and R_{PUB} have a value of 4 k Ω when the output is driving high. R_{PUA} and R_{PUB} are disabled when OE = Low. This feature provides lower static power consumption (when the I/Os are passing a low), and supports lower V_{OL} values for the same size pass-gate transistor, and helps improve simultaneous switching performance.

9.4 Device Functional Modes

The TXS0108E device has two functional modes, enabled and disabled. To disable the device set the OE pin input low, which places all I/Os in a high impedance state. Setting the OE pin input high enables the device.

10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The TXS0108E can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The device is ideal for use in applications where an open-drain driver is connected to the data I/Os. The device is appropriate for applications where a push-pull driver is connected to the data I/Os, but the TXB0104 device, (SCES650) *4-Bit Bidirectional Voltage-Level Translator* might be a better option for such push-pull applications. The device is a semi-buffered auto-direction-sensing voltage translator design is optimized for translation applications (for example, MMC Card Interfaces) that require the system to start out in a low-speed open-drain mode and then switch to a higher speed push-pull mode.

10.2 Typical Application

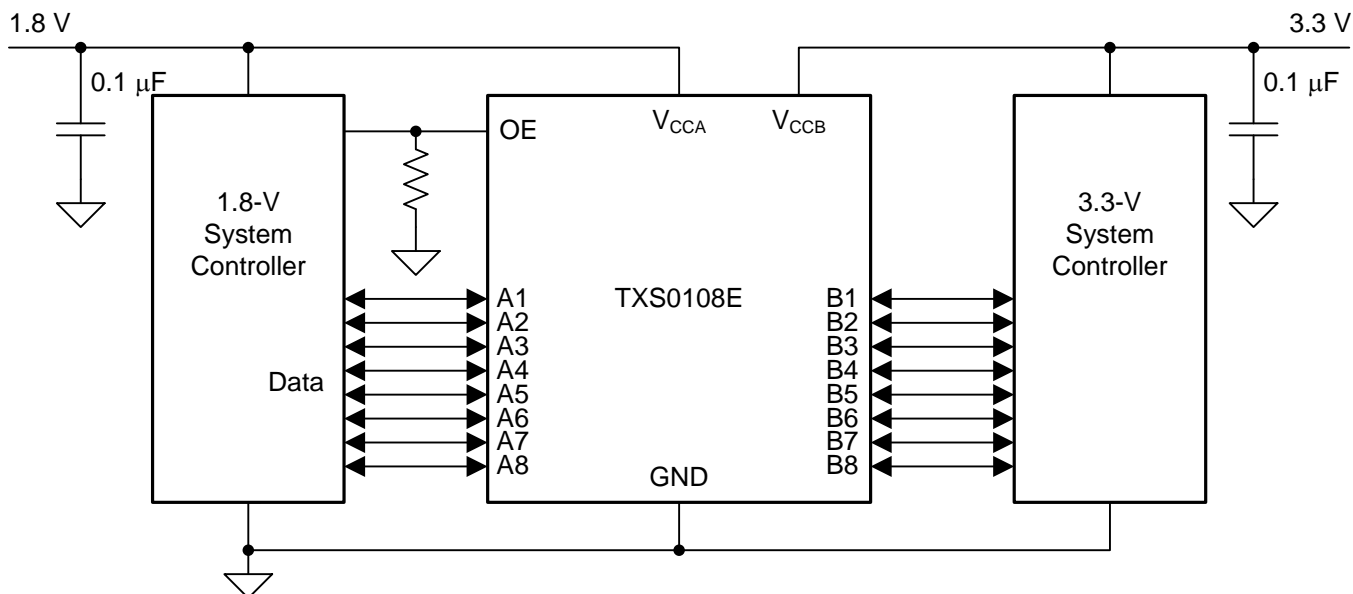


Figure 10. Typical Application Circuit

10.2.1 Design Requirements

For this design example, use the parameters listed in Table 2. Ensure that $V_{CCA} \leq V_{CCB}$.

Table 2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.4 V to 3.6 V
Output voltage range	1.65 V to 5.5 V

10.2.2 Detailed Design Procedure

To begin the design process, determine the following:

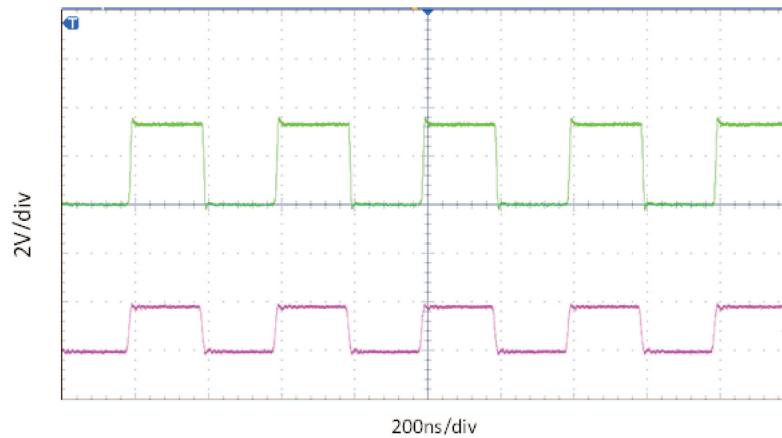
- Input voltage range
 - Use the supply voltage of the device that is driving the TXS0108E device to determine the input voltage range. For a valid logic high the value must exceed the V_{IH} of the input port. For a valid logic low the value

must be less than the V_{IL} of the input port.

- Output voltage range
 - Use the supply voltage of the device that the TXS0108E device is driving to determine the output voltage range.
 - The TXS0108E device has smart internal pull-up resistors. External pull-up resistors can be added to reduce the total RC of a signal trace if necessary.
- An external pull-down resistor decreases the output VOH and VOL. Use [Equation 1](#) to calculate the VOH as a result of an external pull-down resistor.

$$V_{OH} = V_{CCX} \times R_{PD} / (R_{PD} + 4 \text{ k}\Omega) \quad (1)$$

10.2.3 Application Curves



$$V_{CCA} = 1.8 \text{ V}$$

$$V_{CCB} = 3.3 \text{ V}$$

Figure 11. Level-Translation of a 2.5-MHz Signal

11 Power Supply Recommendations

During operation, ensure that $V_{CCA} \leq V_{CCB}$ at all times. The sequencing of each power supply will not damage the device during the power up operation, so either power supply can be ramped up first. The output-enable (OE) input circuit is designed so that it is supplied by V_{CCA} and when the (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pull-down resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pull-down resistor to ground is determined by the current-sourcing capability of the driver.

12 Layout

12.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies. Place the capacitors as close as possible to the VCCA, VCCB pin and GND pin.
- Short trace lengths should be used to avoid excessive loading.
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one shot duration, approximately 30 ns, ensuring that any reflection encounters low impedance at the source driver.

12.2 Layout Example

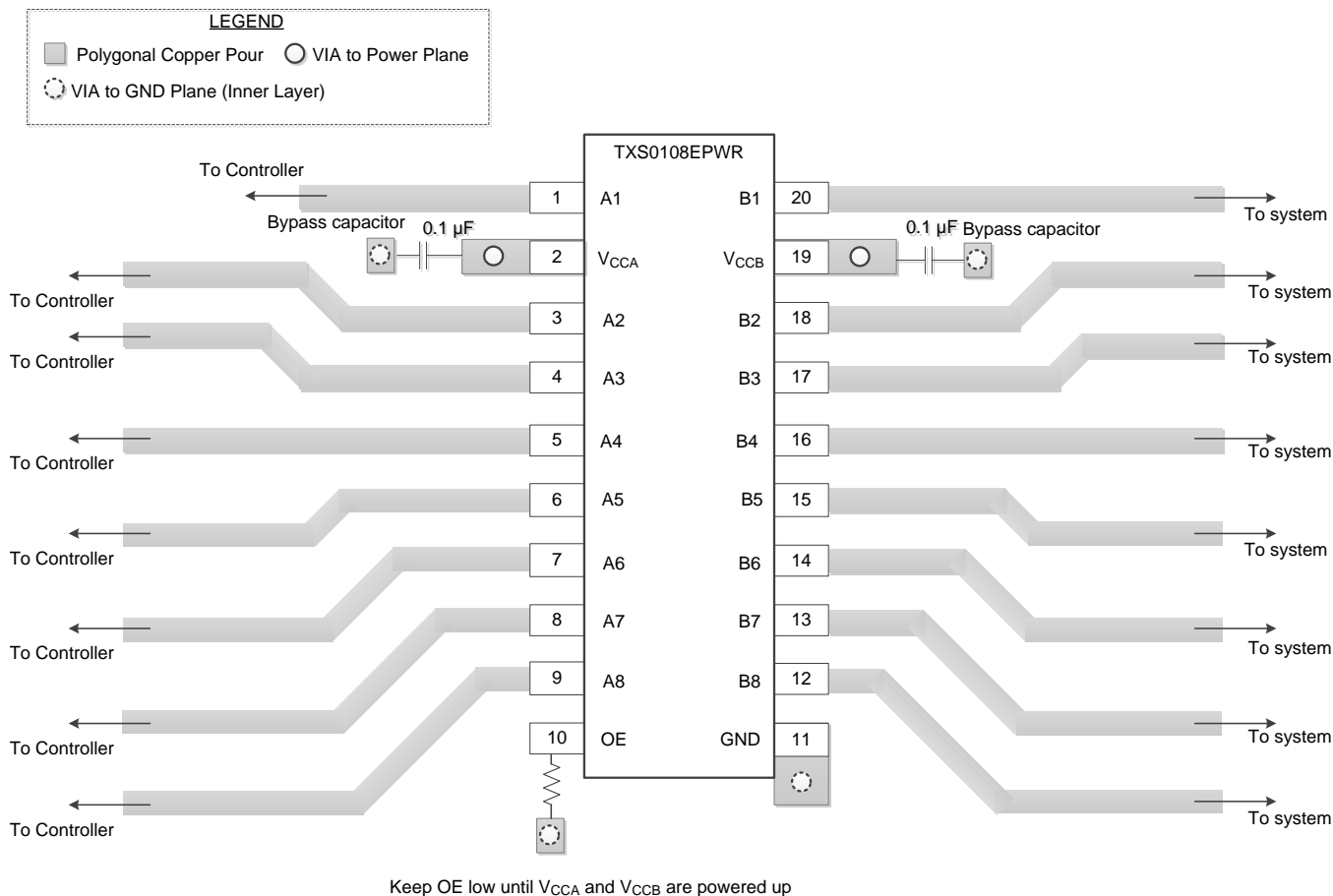


Figure 12. Layout Example

13 Device and Documentation Support

13.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.2 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TXS0108EPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YF08E	Samples
TXS0108EPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	YF08E	Samples
TXS0108ERGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YF08E	Samples
TXS0108EZXYR	ACTIVE	BGA MICROSTAR JUNIOR	ZXY	20	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	YF08E	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

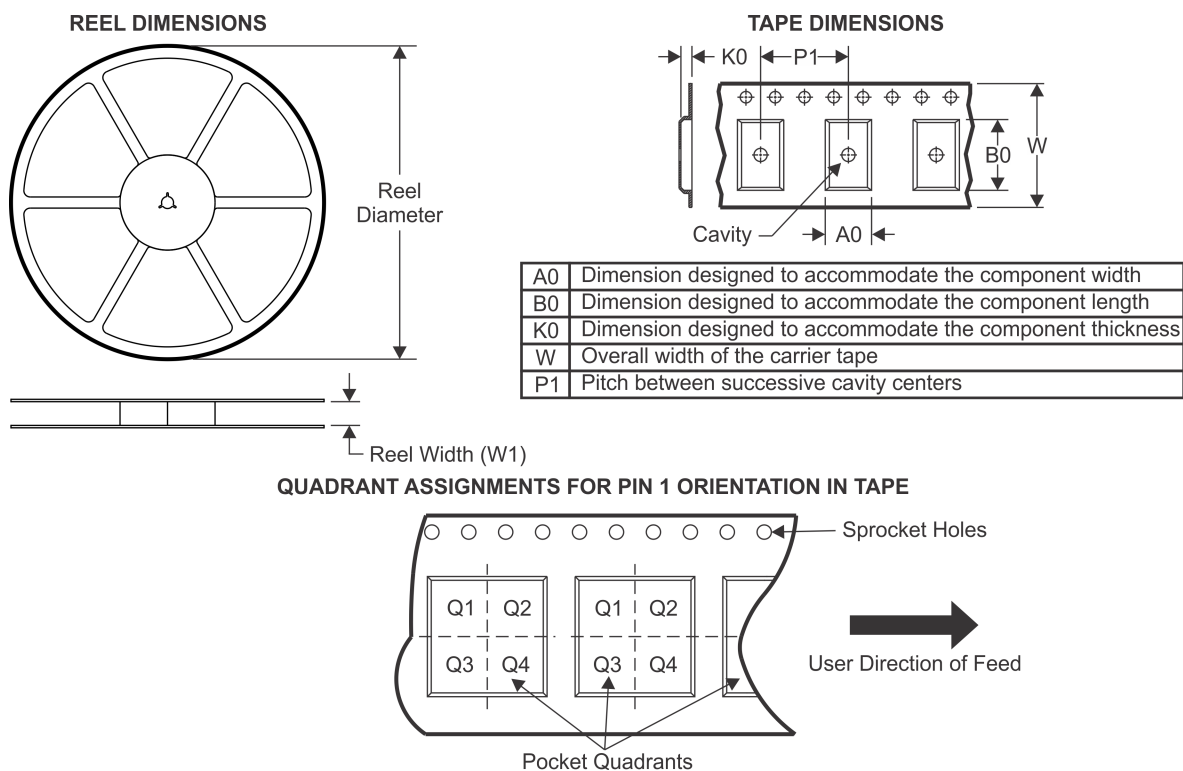
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TXS0108E :

- Automotive: [TXS0108E-Q1](#)

NOTE: Qualified Version Definitions:

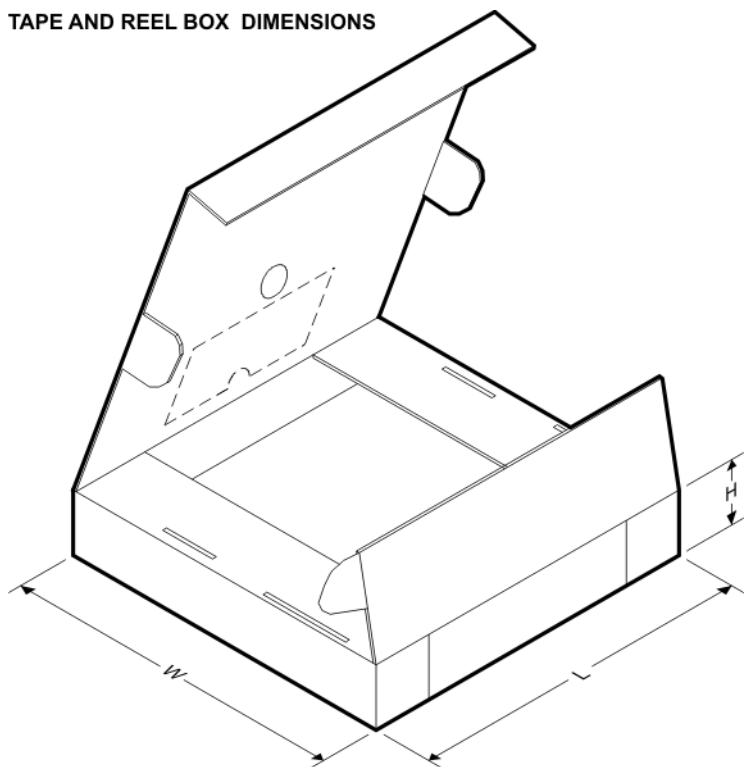
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0108EPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TXS0108ERGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1
TXS0108EZXYR	BGA MICROSTAR JUNIOR	ZXY	20	2500	330.0	12.4	2.8	3.3	1.0	4.0	12.0	Q2

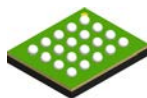
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0108EPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
TXS0108ERGYR	VQFN	RGY	20	3000	367.0	367.0	35.0
TXS0108EZXYR	BGA MICROSTAR JUNIOR	ZXY	20	2500	336.6	336.6	28.6

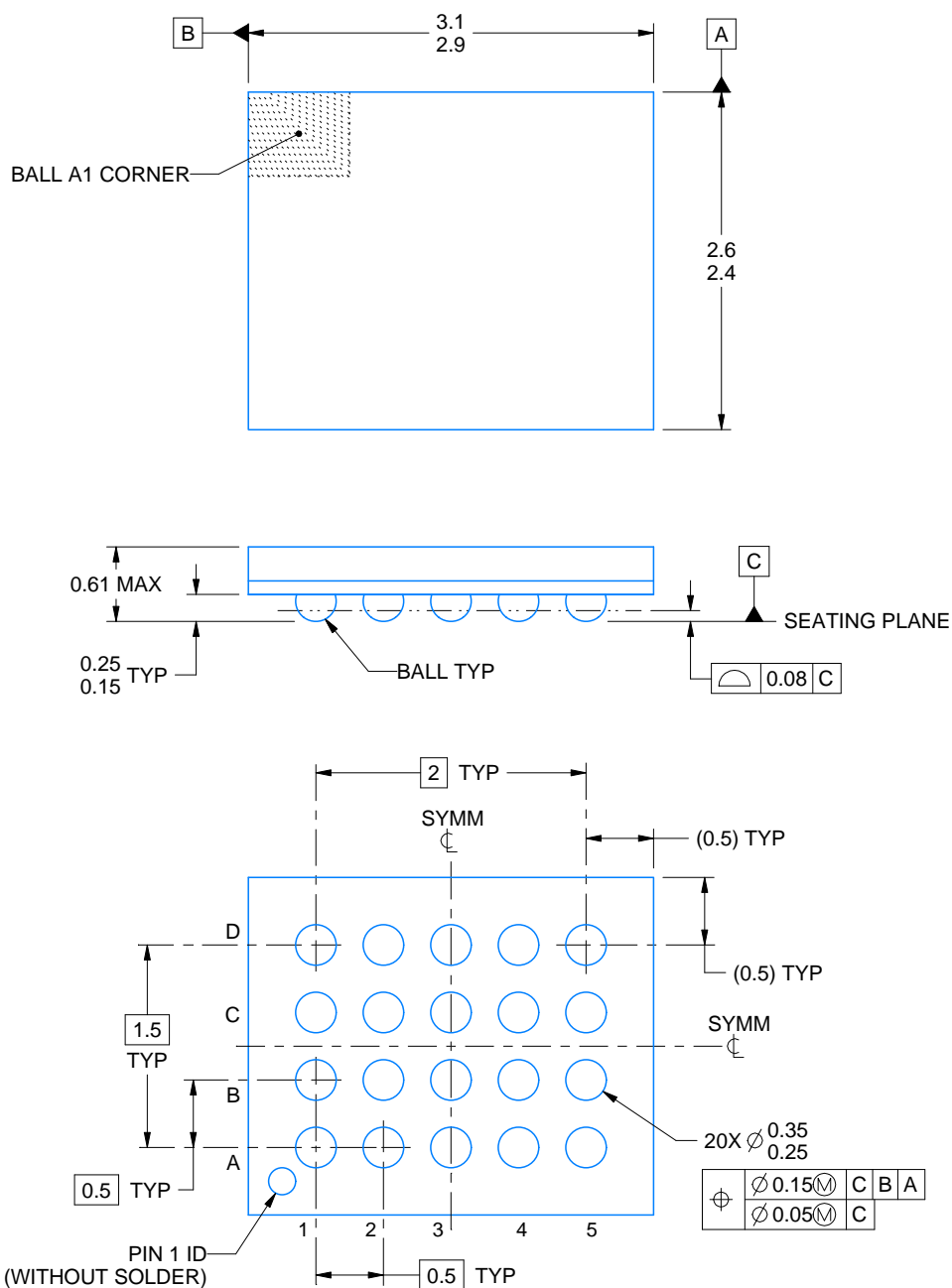
ZXY0020A



PACKAGE OUTLINE

VFBGA - 0.61 mm max height

PLASTIC BALL GRID ARRAY



4222996/A 12/2016

NOTES:

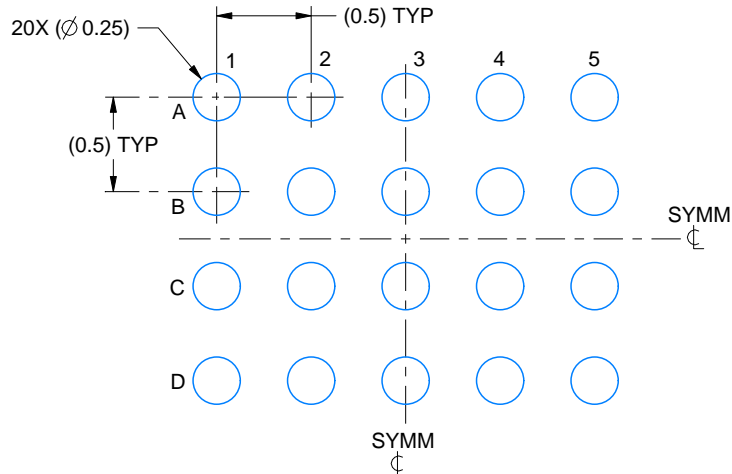
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

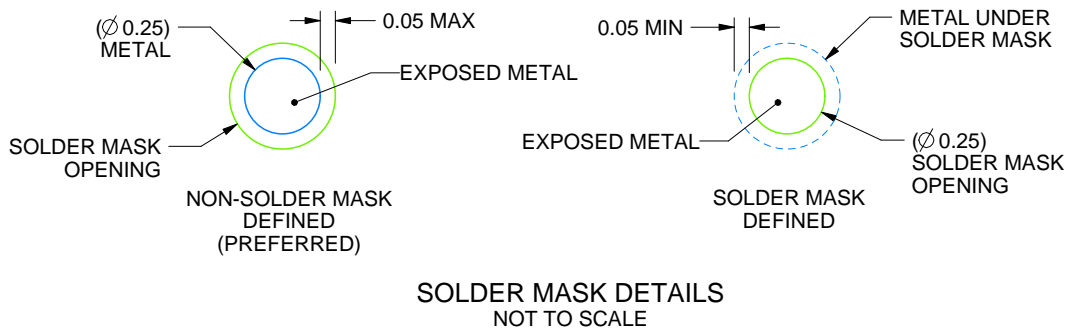
ZXY0020A

VFBGA - 0.61 mm max height

PLASTIC BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X



4222996/A 12/2016

NOTES: (continued)

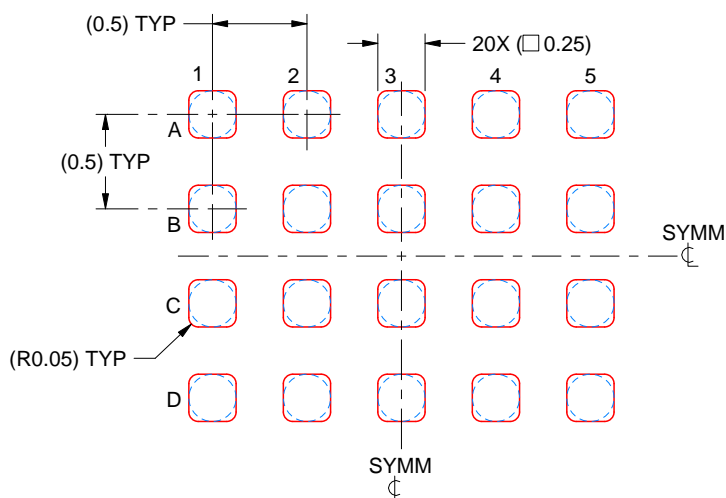
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

EXAMPLE STENCIL DESIGN

ZXY0020A

VFBGA - 0.61 mm max height

PLASTIC BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE: 25X

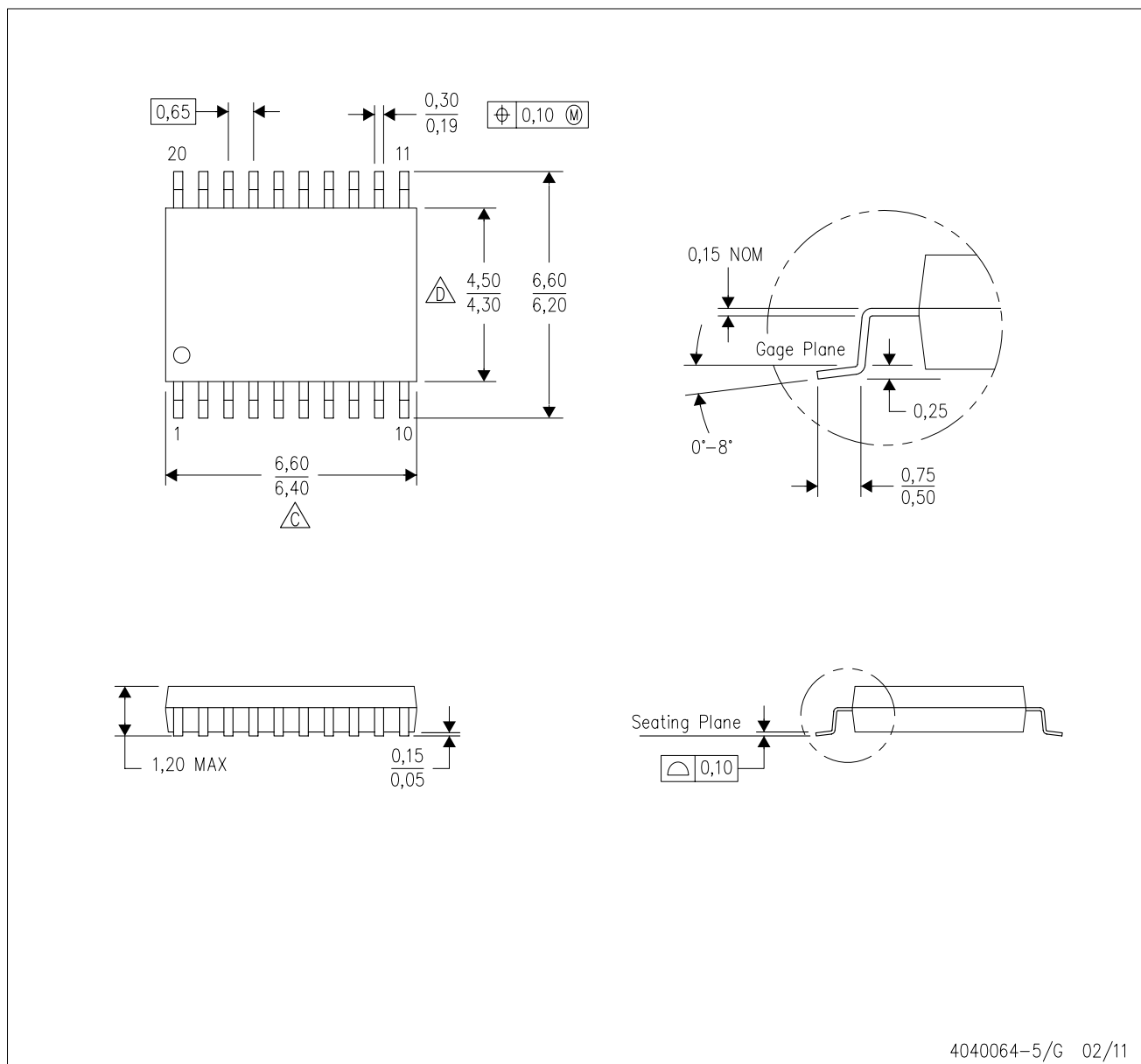
4222996/A 12/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

PW (R-PDSO-G20)

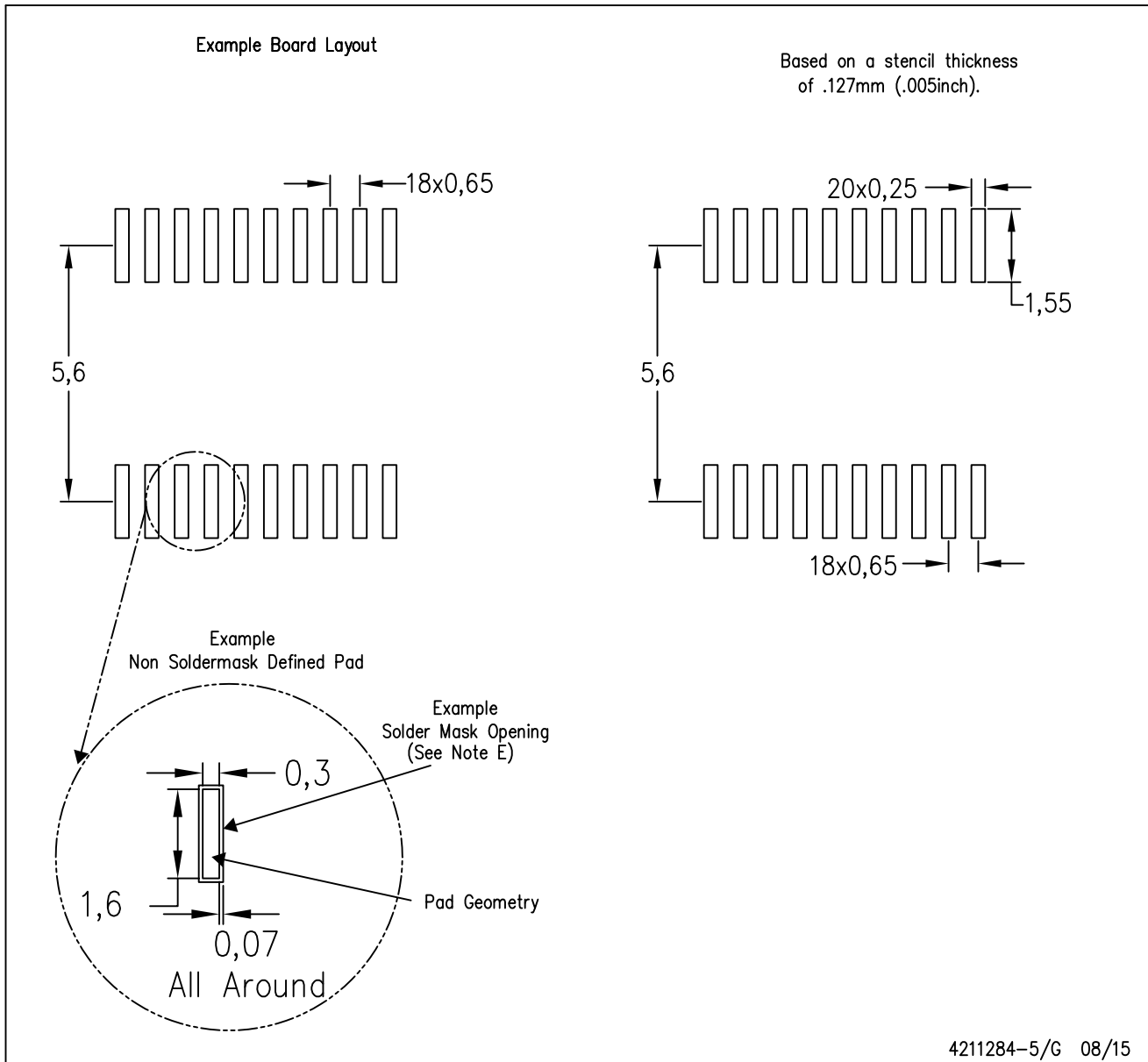
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G20)

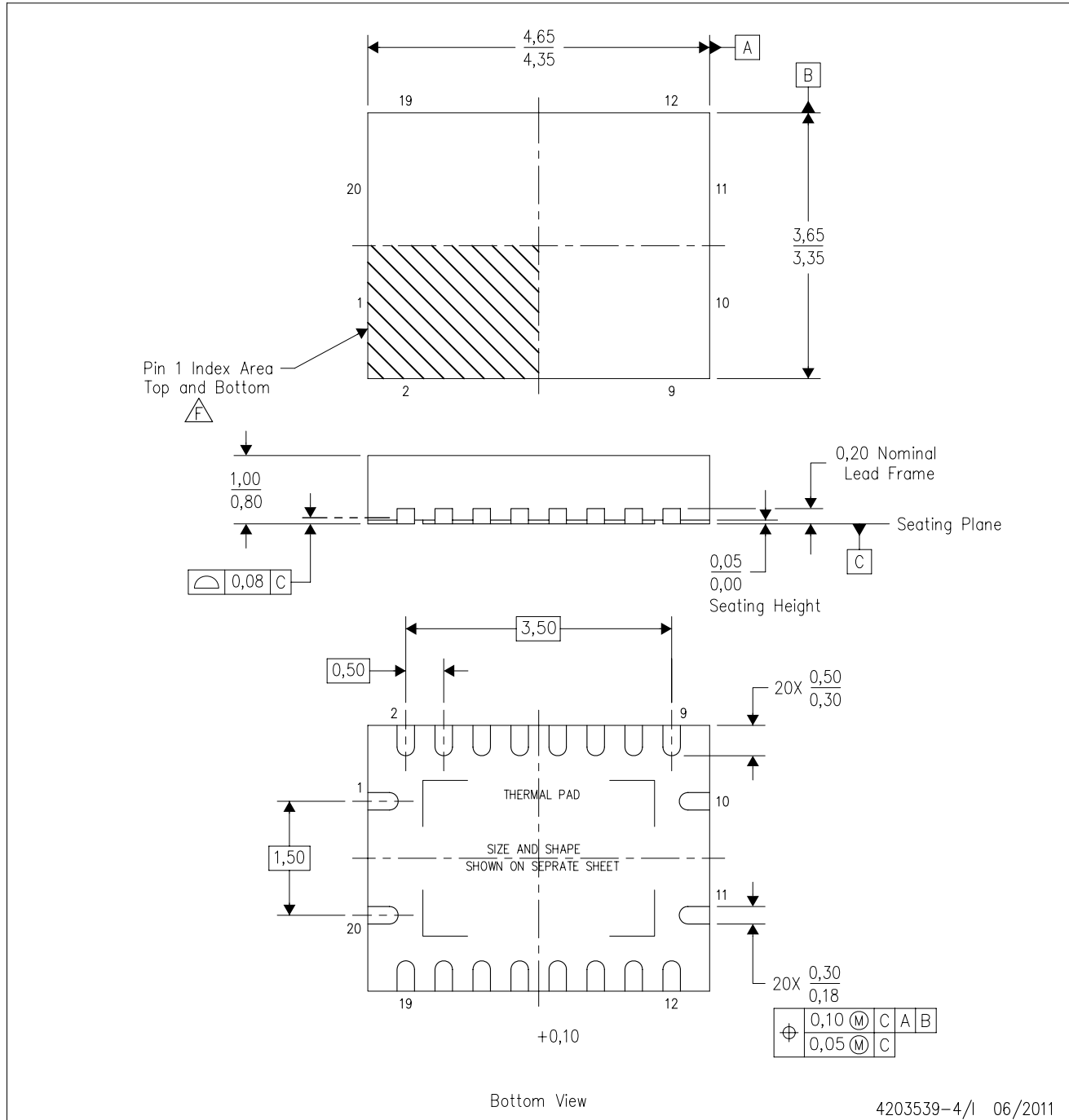
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
 - Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N20)

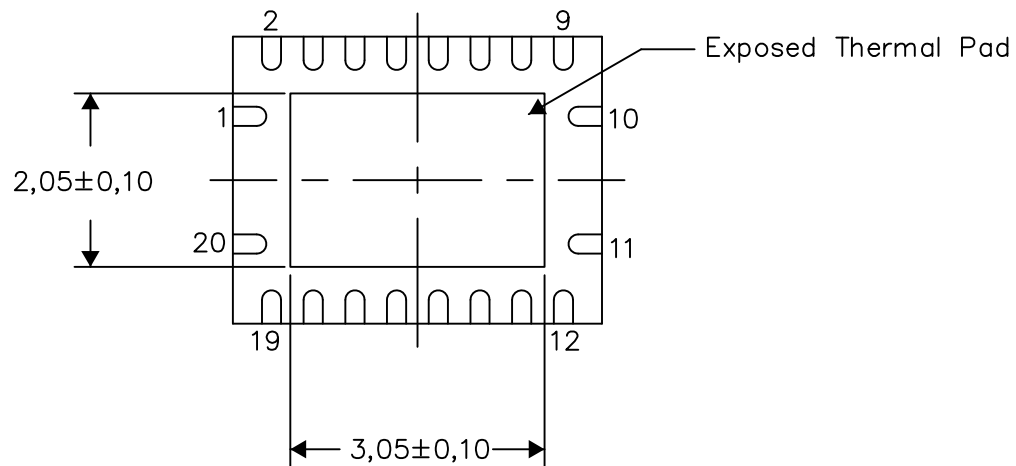
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

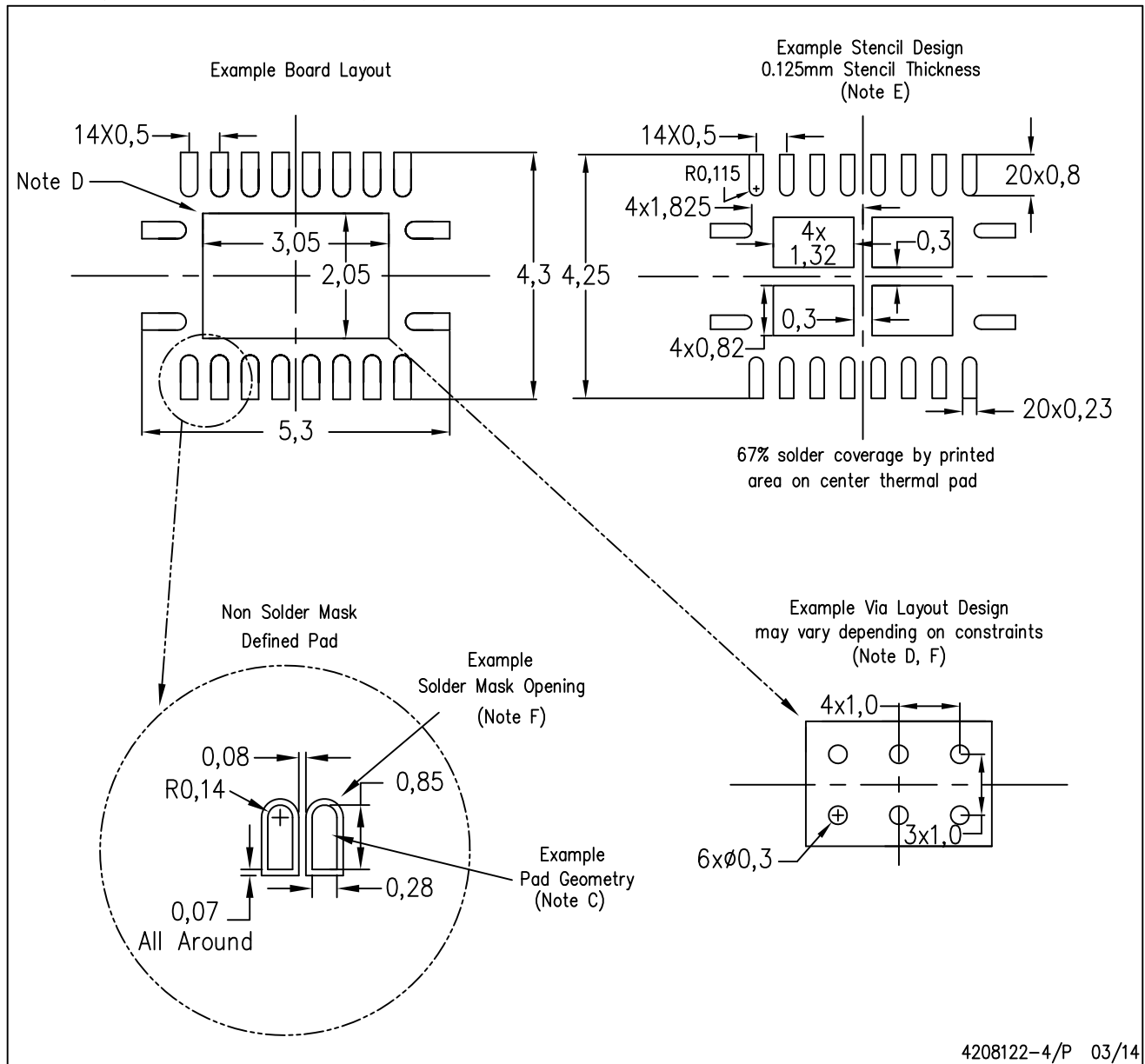
Exposed Thermal Pad Dimensions

4206353-4/P 03/14

NOTE: All linear dimensions are in millimeters

RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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